

# Interstitial oxygen tailoring by various surface treatments and how it impacts Q<sub>0</sub>

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#### **Extensive HPR**

[Ghanbari, R. TTC Workshop 2022, Aomori]



## 18x HPR is not beneficial for Q<sub>0</sub>



#### **Different treatments – same rf behaviour**



#### It's not the cavity!



## Dip is deeper for $18 \times HPR - \Delta f_{tot}$ similar



Cavity	Treatment	∆f <sub>dip</sub> /kHz
1DE19	4.5h @ 335°C	1.1
1AC02	3.25h @ 335°C	1.4
1RI04	3h @ 250°C	0.9
1DE07	20h @ 250°C	2.0
1DE79	18xHPR + 3h @ 300°C	3.9

How much O is good? | Marc Wenskat | 5.12. - TTC Workshop @ FNAL

#### What information is encoded in f vs. T?





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#### Microscopic model for disordered superconductor

- An increased oxygen concentration reduces T<sub>c</sub> of Nb by 0.93K per 1 at.%
  - to have a dip minimum at 9.1K we would need  $\approx 0.2$  at.%
  - "end of dip" around 8.9K  $\approx$  0.3 at.%
- Solubility limit of O in Nb is 1 at.% @ 500°C and 0.33 at.% at 145°C

[Benvenuti, C., et al. 10<sup>th</sup> *SRF* (2001): p441.] [Kolchin, O.P., et al. *Soviet Atomic Energy 45 (4) (1978): p999.*]

- We have shown that C diffusion speed in Nb along GB vary with GB orientation, increasing disorder by [Dangwal Pandey, A., et al. Appl. Phys. Lett. 119(2021): 194102]
  - → Assume same is true for O: not homogenous distributed within the rf layer, but clusters with uneven O-concentration
- $\rightarrow$  Expect non-constant (gaussian shaped) T<sub>c</sub> reduction
- $\rightarrow$  Lowest T<sub>c</sub> equal to the max. at.% concentration at RT ( $\approx 0.33$  at.%)
- $\rightarrow$  Only locally saturated not globally. If SIMS spot size  $\approx$  multiple grains, obtained c<sub>0</sub> below saturation limit

[Desorbo, W. Phys. Rev. 132 (1963): 107.]

#### **Disordered superconductor show dip**

[Barra, M., et al. SUST 18.3 (2005): 271.]



#### If it acts the same – is it the same?



# 3h@300°C ≠ 3h@300°C

#### [Wenskat, M., et al SRF2023 TUIBA02.] [Wenskat, M., et al Supercond. Sci. Technol. 36 (2023) 015010 (11pp).]



# **High thermal budget**



- Diffuse O out of RF layer
  - $\rightarrow$  HFQS reappears and  $\Delta f_{tot}$  /  $\Delta f_{dip}$  decreases again



Cavity	Treatment	∆f <sub>tot</sub> /kHz	∆f <sub>dip</sub> /kHz
LDE19	4.5h @ 335°C	11.7	1.1
AC02	3.25h @ 335°C	12.3	1.4
LRI04	3h @ 250°C	18.4	0.9
LDE12	3h @350°C	8.3	0.52

# Is there an optimal O-concentration?



# **Correlation with thermal budget?**

Assumed  $\Delta f$  is depends  $c_0 \dots$ 

and we know that NSF c\_0 goes down with larger thermal budget / larger  $\langle z \rangle$  ...

some correlation of  $Q_0$  with  $\langle z \rangle$  expected as well – yet weaker as Fick's law does not accomodate uneven GB diffusion / saturation effects



### Conclusion

- Too high c<sub>o</sub> near the surface is not good
  - 18xHPR before midT of 1DE7
  - 1xmidT vs. 2xmidT of 1DE10
- Too low c<sub>o</sub> leads to HFQS again
  1DE12 or every 800°C reset
- Optimal recipe depends on furnace "thermal budget"
  1DE10 vs. 1DE18
- Sweet spot for Q<sub>0</sub> seems to exist right amount of disorder ?
   continue investigation & model building (Δf<sub>tot</sub> vs. Δf<sub>dip</sub>, E<sub>acc</sub>, grain mapping)

#### Thanks...

- to **DESY** for the cavity measurements
- to **you** for listening
- to the **conveners** for the opportunity to present this work

#### **Questions?**



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# Back Up

#### **Current Redistribution**

[Checchin, M. et al., Appl. Phys. Lett. 117, 032601 (2020)] [Pambianchi, M. et al., Phys. Rev. B 50, 13659]



#### Consequence: Currents shifted away from the surface where "lossy mechanism(s)" occur

#### **Frequency shift is frequency dependent**



- Q<sub>n</sub> = n x 433MHz
- Lower frequency  $f_{op} \rightarrow \text{lower } \Delta f_{tot}$
- That is because Γ is frequency dependent
- If the dip is caused by current redistribution  $\rightarrow \Delta f_{dip}$  should depend on  $f_{op}$  as well